

PS2705-1

HIGH ISOLATION VOLTAGE AC INPUT RESPONSE TYPE SOP MULTI PHOTOCOUPLER

R08DS0093EJ0301 Rev.3.01 July 19, 2019

DESCRIPTION

The PS2705-1 is an optically coupled isolator containing a GaAs light emitting diode and an NPN silicon phototransistor.

This package is SOP (Small Outline Package) type and has shield effect to cut off ambient light.

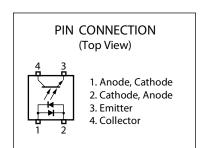
It is designed for high density mounting applications.

FEATURES

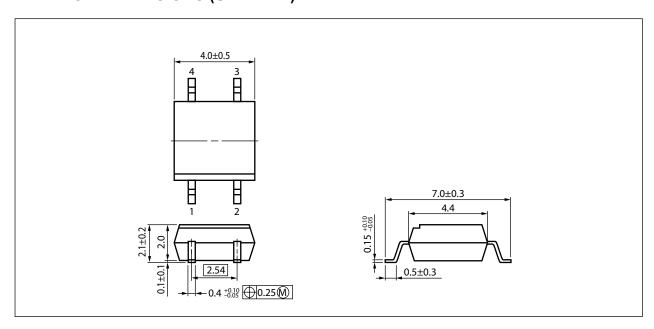
- AC input response
- High isolation voltage (BV = 3 750 Vr.m.s.)
- High current transfer ratio (CTR = 100% TYP.)
- SOP (Small Outline Package) type
- High-speed switching (tr = 3 μ s TYP., tf = 5 μ s TYP.)
- Ordering number of taping product: PS2705-1-F3
- · Safety standards
 - UL approved: UL1577, Single protection
 - CSA approved: CAN/CSA-C22.2 No. 62368-1, Basic/Supplementary insulation
 - BSI approved: BS EN 62368-1, Basic/Supplementary insulation
 - SEMKO approved: EN 62368-1, IEC 62368-1, Basic/Supplementary insulation
 - NEMKO approved: EN 62368-1, Basic/Supplementary insulation
 - FIMKO approved: EN 62368-1, Basic/Supplementary insulation
 - DEMKO approved: EN 62368-1, Basic/Supplementary insulation
 - VDE approved: DIN EN 60747-5-5 (Option)

APPLICATIONS

- Hybrid IC
- Telephone/FAX
- FA/OA equipment
- · Programmable logic controllers
- Power supply



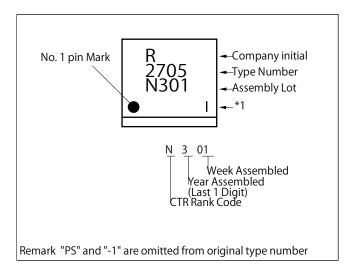
PACKAGE DIMENSIONS (UNIT: mm)



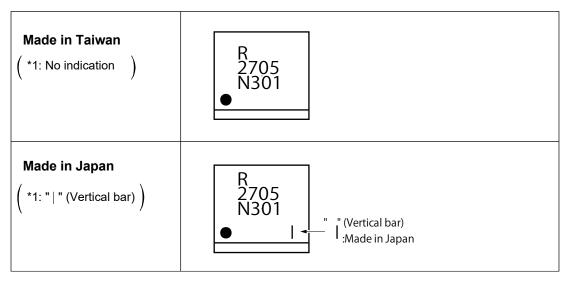
PHOTOCOUPLER CONSTRUCTION

Parameter	Unit (MIN.)
Air Distance	5 mm
Creepage Distance	5 mm
Isolation Distance	0.3 mm

MARKING EXAMPLE



Note: Bar indication contents of *1



ORDERING INFORMATION

Part Number	Order Number	Solder Plating Specification	Packing Style	Safety Standard Approval	Application Part Number*1
PS2705-1-F3	PS2705-1-F3-A	Pb-Free	Embossed Tape 3 500 pcs/reel	Standard products (UL, BSI, CSA, SEMKO, NEMKO, FIMKO, DEMKO approved)	PS2705-1
PS2705-1-V-F3	PS2705-1-V-F3-A		Embossed Tape 3 500 pcs/reel	UL, CSA, BSI, SEMKO, NEMKO, FIMKO, DEMKO, DIN EN 60747-5-5 approved	

Note: *1. For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C, unless otherwise specified)

	Parameter	Symbol	Ratings	Unit
Diode	Forward Current (DC)	lF	± 50	mA
	Power Dissipation Derating	⊿P _D /°C	0.8	mW/°C
	Power Dissipation	PD	80	mW
	Peak Forward Current*1	I _{FP}	± 1	Α
Transistor	Collector to Emitter Voltage	Vceo	40	V
	Emitter to Collector Voltage	V _{ECO}	6	V
	Collector Current	Ic	80	mA
	Power Dissipation Derating	⊿Pc/°C	1.5	mW/°C
	Power Dissipation	Pc	150	mW
Isolation Voltage*2		BV	3 750	Vr.m.s.
Operating Ambient Temperature		TA	-55 to +100	°C
Storage Temperature		T _{stg}	-55 to +150	°C

Note: *1. PW = 100 μ s, Duty Cycle = 1%

^{*2.} AC voltage for 1 minute at T_A = 25°C, RH = 60% between input and output. Pins 1-2 shorted together, 3-4 shorted together.

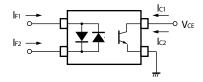
ELECTRICAL CHARACTERISTICS ($T_A = 25$ °C)

	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	V _F	I _F = ± 5 mA		1.1	1.4	V
	Terminal Capacitance	Ct	V = 0 V, f = 1 MHz		60		pF
Transistor	Collector to Emitter Dark Current	I _{CEO}	I _F = 0 mA, V _{CE} = 40 V			100	nA
Coupled	Current Transfer Ratio (I _C /I _F)*1	CTR	$I_F = \pm 5 \text{ mA}, V_{CE} = 5 \text{ V}$	50	100	300	%
	CTR Ratio*2	CTR ₁ / CTR ₂	$I_F = \pm 5$ mA, $V_{CE} = 5$ V	0.3	1.0	3.0	
	Collector Saturation Voltage	V _{CE (sat)}	$I_F = \pm 10 \text{ mA}, I_C = 2 \text{ mA}$			0.3	V
	Isolation Resistance	R _{I-O}	$V_{I-O} = 1 \text{ kV}_{DC}$	10 ¹¹			Ω
	Isolation Capacitance	C _{I-O}	V = 0 V, f = 1 MHz		0.4		pF
	Rise Time*3	t _r	$V_{CC} = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega$		3		μS
	Fall Time*3	t _f			5		
	Turn-on Time*3	t _{on}			5		
	Turn-off Time*3	t _{off}			4		

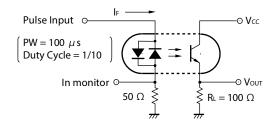
Note: *1. CTR rank

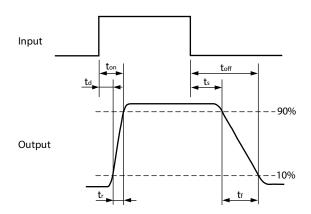
M: 50 to 150 (%) L: 100 to 300 (%) N: 50 to 300 (%)

*2. $CTR_1 = I_{C1}/I_{F1}$, $CTR_2 = I_{C2}/I_{F2}$

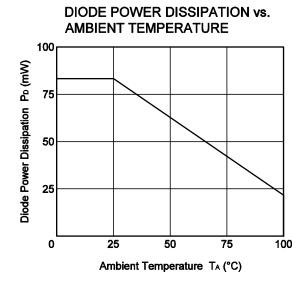


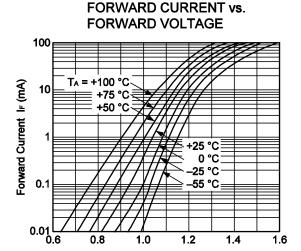
*3. Test Circuit for Switching Time



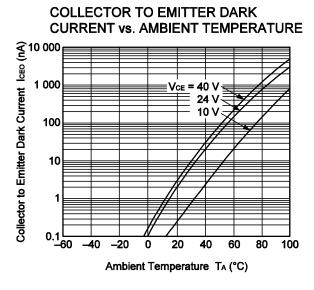


TYPICAL CHARACTERISTICS (T_A = 25°C, unless otherwise specified)



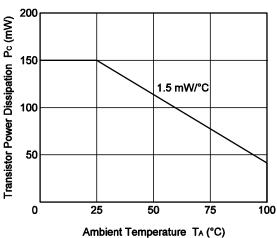


Forward Voltage V_F (V)

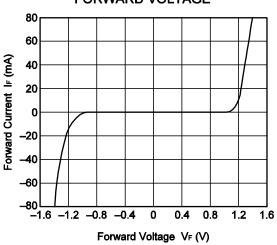


Remark The graphs indicate nominal characteristics.

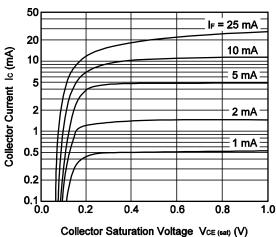
TRANSISTOR POWER DISSIPATION vs. AMBIENT TEMPERATURE



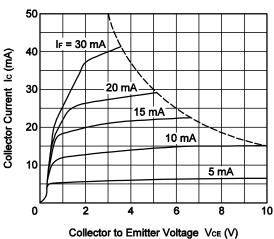
FORWARD CURRENT vs. **FORWARD VOLTAGE**



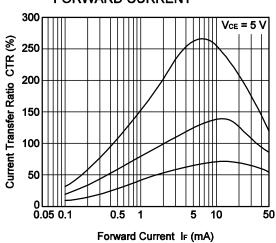
COLLECTOR CURRENT vs. COLLECTOR SATURATION VOLTAGE



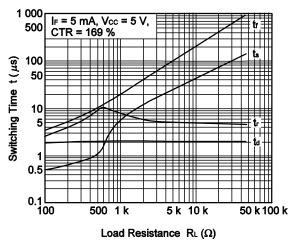
COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE



CURRENT TRANSFER RATIO vs. FORWARD CURRENT

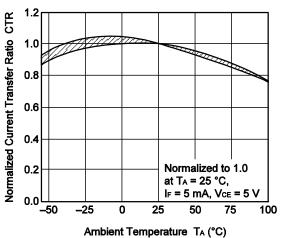


SWITCHING TIME vs. LOAD RESISTANCE

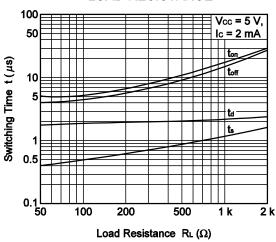


Remark The graphs indicate nominal characteristics.

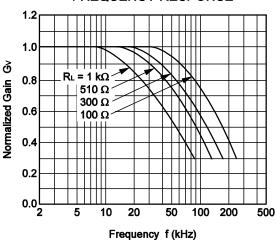
NORMALIZED CURRENT TRANSFER RATIO vs. AMBIENT TEMPERATURE



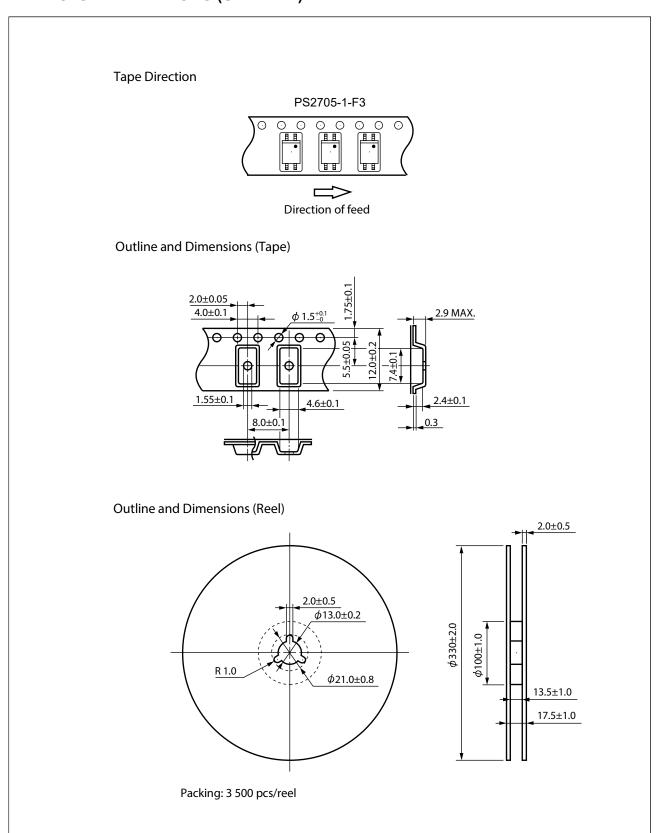
SWITCHING TIME vs. LOAD RESISTANCE



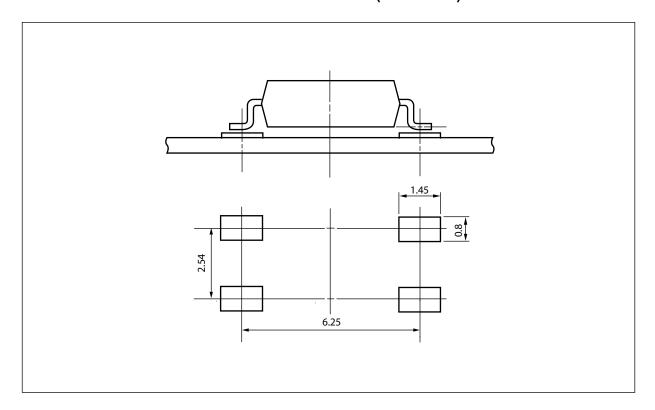
FREQUENCY RESPONSE



TAPING SPECIFICATIONS (UNIT: mm)



RECOMMENDED MOUNT PAD DIMENSIONS (UNIT: mm)



Remark All dimensions in this figure must be evaluated before use.

NOTES ON HANDLING

- 1. Recommended soldering conditions
 - (1) Infrared reflow soldering
 - Peak reflow temperature 260°C or below (package surface temperature)
 - · Time of peak reflow temperature 10 seconds or less Time of temperature higher than 220°C 60 seconds or less
 - Time to preheat temperature from 120 to 180°C
 - Number of reflows
 - Flux

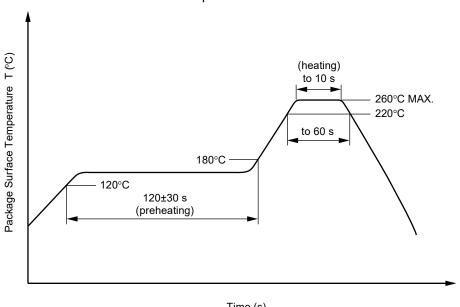
120±30 s

Three

Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of

0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



Time (s)

(2) Wave soldering

 Temperature 260°C or below (molten solder temperature)

 Time 10 seconds or less

 Preheating conditions 120°C or below (package surface temperature)

 Number of times One (Allowed to be dipped in solder including plastic mold portion.) Rosin flux containing small amount of chlorine (The flux with a maximum • Flux

chlorine content of 0.2 Wt% is recommended.)

(3) Soldering by Soldering Iron

 Peak Temperature (lead part temperature) 350°C or below Time (each pins) 3 seconds or less

• Flux Rosin flux containing small amount of chlorine

(The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

(a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead

(4) Cautions

Flux Cleaning

Avoid cleaning with Freon based or halogen-based (chlorinated etc.) solvents.

• Do not use fixing agents or coatings containing halogen-based substances.

- 2. Cautions regarding noise
 - Be aware that when voltage is applied suddenly between the photocoupler's input and output or between collector-emitters at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.
- 3. Measurement conditions of current transfer ratios (CTR), which differ according to photocoupler Check the setting values before use, since the forward current conditions at CTR measurement differ according to product.

When using products other than at the specified forward current, the characteristics curves may differ from the standard curves due to CTR value variations or the like. This tendency may sometimes be obvious, especially below $I_F = 1$ mA.

Therefore, check the characteristics under the actual operating conditions and thoroughly take variations or the like into consideration before use.

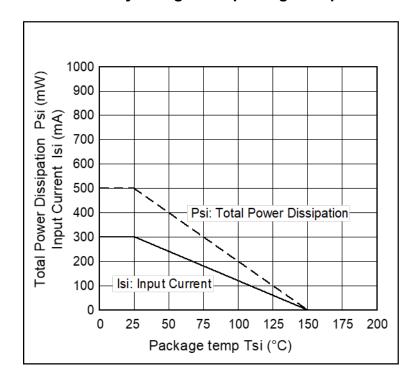
USAGE CAUTIONS

- 1. Protect against static electricity when handling.
- 2. Avoid storage at a high temperature and high humidity.

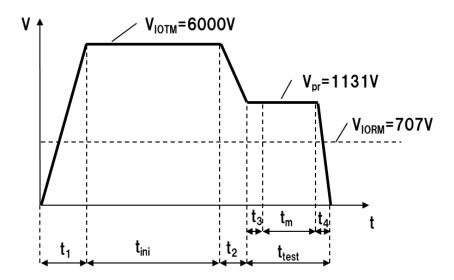
SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

Parameter	Symbol	Rating	Unit
Climatic test class (IEC 60068-1/DIN EN 60068-1)		55/100/21	
Dielectric strength			
maximum operating isolation voltage	U _{IORM}	707	V_{peak}
Test voltage (partial discharge test, procedure a for type test and	U _{pr}	1 131	V_{peak}
random test)			
Upr = $1.6 \times U_{IORM}$, $P_d < 5 pC$			
Test voltage (partial discharge test, procedure b for all devices)	Upr	1 325	V_{peak}
U_{pr} = 1.875 × U_{IORM} , P_d < 5 pC			
Highest permissible overvoltage	U _{IOTM}	6 000	V_{peak}
Degree of pollution (IEC 60664-1/DIN EN 60664-1 (VDE 0110-1)		2	
Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303-11))	CTI	175	
Material group (IEC 60664-1/DIN EN 60664-1 (VDE 0110-1))		III a	
Storage temperature range	T _{stg}	-55 to +150	°C
Operating temperature range	T _A	-55 to +100	°C
Isolation resistance, minimum value			
$V_{IO} = 500 \text{ V dc at } T_A = 25^{\circ}\text{C}$	Ris MIN.	10 ¹²	Ω
V _{IO} = 500 V dc at T _A MAX. at least 100°C	Ris MIN.	10 ¹¹	Ω
Safety maximum ratings (maximum permissible in case of fault, see			
thermal derating curve)			
Package temperature	Tsi	150	°C
Current (input current I _F , Psi = 0)	Isi	300	mA
Power (output or total power dissipation)	Psi	500	mW
Isolation resistance			
V _{IO} = 500 V dc at T _A = Tsi	Ris MIN.	10 ⁹	Ω

Dependence of maximum safety ratings with package temperature



Method a) Destructive Test, Type and Sample Test



 $t_1,t_2=1$ to 10 sec

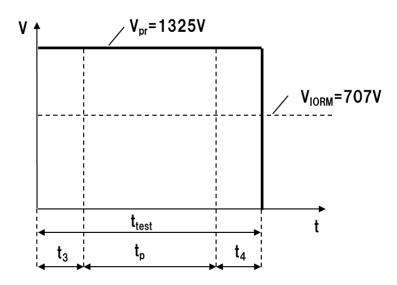
 $t_3, t_4 = 1 \text{ sec}$

 $t_{m (PARTIAL DISCHARGE)} = 10 \text{ sec}$

t_{test}=12 sec

t_{ini}=60 sec

Method b) Non-destructive Test, 100% Production Test



 $t_3,t_4=0.1 \text{ sec}$

 $t_{p (PARTIAL DISCHARGE)} = 1.0 sec$

 t_{test} =1.2 sec

Caution

GaAs Products

This product uses gallium arsenide (GaAs).

GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.

- Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
- Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
- 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
- Do not burn, destroy, cut, crush, or chemically dissolve the product.
- Do not lick the product or in any way allow it to enter the mouth.

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Renesas Electronics Corporation TOYOSU FORESIA, 3-2-24 Toyosu, Koto-ku, Tokyo 135-0061, Japan

Renesas Electronics America Inc. 1001 Murphy Ranch Road, Milpitas, CA 95035, U.S.A. Tel: +1-408-432-8888, Fax: +1-408-434-5351

Renesas Electronics Canada Limited 9251 Yonge Street, St Tel: +1-905-237-2004 eet, Suite 8309 Richmond Hill, Ontario Canada L4C 9T3

Renesas Electronics Europe GmbH Arcadiastrasse 10, 40472 Düsseldorf, Germany Tel: +49-211-6503-0, Fax: +49-211-6503-1327

Renesas Electronics (China) Co., Ltd.
Room 101-T01, Floor 1, Building 7, Yard No. 7, 8th Street, Shangdi, Haidian District, Beijing 100085, China Tel: +86-10-8235-1155, Fax: +86-10-8235-7679

Renesas Electronics (Shanghai) Co., Ltd.

Unit 301, Tower A, Central Towers, 555 Langao Road, Putuo District, Shanghai 200333, China Tel: +86-21-2226-0888, Fax: +86-21-2226-0999

Renesas Electronics Hong Kong Limited
Unit 1601-1611, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong Tel: +852-2265-6688, Fax: +852 2886-9022

Renesas Electronics Talwan Co., Ltd. 13F, No. 363, Fu Shing North Road, Taipei 10543, Taiwan Tel: +886-2-8175-9600, Fax: +886 2-8175-9670

Renesas Electronics Singapore Pte. Ltd.
80 Bendemeer Road, Unit #06-02 Hyflux Innovation Centre, Singapore 339949
Tel: +65-6213-0200, Fax: +65-6213-0300

Renesas Electronics Malaysia Sdn.Bhd.
Unit No 3A-1 Level 3A Tower 8 UOA Business Park, No 1 Jalan Pengaturcara U1/51A, Seksyen U1, 40150 Shah Alam, Selangor, Malaysia Tel: +60-3-5022-1288, Fax: +60-3-5022-1290

Renesas Electronics India Pvt. Ltd.
No.777C, 100 Feet Road, HAL 2nd Stage, Indiranagar, Bangalore 560 038, India Tel: +91-80-67208700

Renesas Electronics Korea Co., Ltd. 17F, KAMCO Yangjae Tower, 262, Gangnam-daero, Gangnam-gu, Seoul, 06265 Korea Tel: +82-2-558-3737, Fax: +82-2-558-5338

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